

Elisa Garcia-Tabares

List of Publications by Year in descending order

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Version: 2024-02-01

25
papers

313
citations

933447

10
h-index

888059

17
g-index

25
all docs

25
docs citations

25
times ranked

403
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-----------|
| 1 | Electrodeposition of copper applied to the manufacture of seamless superconducting rf cavities. <i>Physical Review Accelerators and Beams</i> , 2021, 24, . | 1.6 | 2 |
| 2 | Flow and fracture of austenitic stainless steels at cryogenic temperatures. <i>Engineering Fracture Mechanics</i> , 2021, 258, 108042. | 4.3 | 8 |
| 3 | Effect of strain rate on tensile mechanical properties of high-purity niobium single crystals for SRF applications. <i>Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing</i> , 2020, 797, 140258. | 5.6 | 7 |
| 4 | Role of surface microgeometries on electron escape probability and secondary electron yield of metal surfaces. <i>Scientific Reports</i> , 2020, 10, 250. | 3.3 | 23 |
| 5 | Resistivity Characterization of Molybdenum-Coated Graphite-Based Substrates for High-Luminosity LHC Collimators. <i>Coatings</i> , 2020, 10, 361. | 2.6 | 12 |
| 6 | Optimization of the secondary electron yield of laser-structured copper surfaces at room and cryogenic temperature. <i>Physical Review Accelerators and Beams</i> , 2020, 23, . | 1.6 | 21 |
| 7 | MOVPE growth of GaP on Si with As initial coverage. <i>Journal of Crystal Growth</i> , 2017, 464, 8-13. | 1.5 | 14 |
| 8 | First accelerator test of vacuum components with laser-engineered surfaces for electron-cloud mitigation. <i>Physical Review Accelerators and Beams</i> , 2017, 20, . | 1.6 | 37 |
| 9 | Inorganic photovoltaics – Planar and nanostructured devices. <i>Progress in Materials Science</i> , 2016, 82, 294-404. | 32.8 | 50 |
| 10 | Evolution of silicon bulk lifetime during III–V on Si multijunction solar cell epitaxial growth. <i>Progress in Photovoltaics: Research and Applications</i> , 2016, 24, 634-644. | 8.1 | 22 |
| 11 | Assessment of Rear-Surface Processing Strategies for III–V on Si Multijunction Solar Cells Based on Numerical Simulations. <i>IEEE Transactions on Electron Devices</i> , 2016, 63, 252-258. | 3.0 | 9 |
| 12 | Alternatives for rear-surface passivation in III–V on Si multi-junction solar cells. , 2015, , . | | 0 |
| 13 | Evolution of the silicon bottom cell photovoltaic behavior during III–V on Si multi-junction solar cells production. , 2015, , . | | 1 |
| 14 | Optimizing diffusion, morphology and minority carrier lifetime in Silicon for GaAsP/Si dual-junction solar cells. , 2015, , . | | 0 |
| 15 | Impact of metal-organic vapor phase epitaxy environment on silicon bulk lifetime for III–V-on-Si multijunction solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2014, 124, 17-23. | 6.2 | 33 |
| 16 | Progress toward a Si-plus architecture: epitaxially-integrable Si sub-cells for III-V/Si multijunction photovoltaics. , 2014, , . | | 4 |
| 17 | Numerical simulation and experimental facts about bottom-cell optimization for III-V on Silicon multijunction solar cells. , 2013, , . | | 7 |
| 18 | Understanding phosphorus diffusion into silicon in a MOVPE environment for III–V on silicon solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2013, 116, 61-67. | 6.2 | 19 |

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|----|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----------|
| 19 | Influence of PH ₃ exposure on silicon substrate morphology in the MOVPE growth of III-V on silicon multijunction solar cells. Journal Physics D: Applied Physics, 2013, 46, 445104. | 2.8 | 12 |
| 20 | Optimization of the silicon subcell for III-V on silicon multijunction solar cells: Key differences with conventional silicon technology. AIP Conference Proceedings, 2012, , . | 0.4 | 7 |
| 21 | Impact of a Metal-Organic Vapor Phase Epitaxy Environment on Silicon Substrates for III-V-on-Si Multijunction Solar Cells. Japanese Journal of Applied Physics, 2012, 51, 10ND05. | 1.5 | 8 |
| 22 | Impact of a Metal-Organic Vapor Phase Epitaxy Environment on Silicon Substrates for III-V-on-Si Multijunction Solar Cells. Japanese Journal of Applied Physics, 2012, 51, 10ND05. | 1.5 | 6 |
| 23 | Triple-junction solar cells for ultra-high concentrator applications. , 2011, , . | | 1 |
| 24 | Integration of III-V materials on silicon substrates for multi-junction solar cell applications. , 2011, , . | | 3 |
| 25 | Optimizing bottom subcells for III-V-on-Si multijunction solar cells. , 2011, , . | | 7 |